

74HC245; 74HCT245

Octal bus transceiver; 3-state

Rev. 03 — 31 January 2005

Product data sheet

1. General description

The 74HC245; 74HCT245 is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL).

The 74HC245; 74HCT245 is an octal transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The 74HC245; 74HCT245 features an output enable input ($\overline{OE}$) for easy cascading and a send/receive input (DIR) for direction control. $\overline{OE}$ controls the outputs so that the buses are effectively isolated.

The 74HC245; 74HCT245 is similar to the 74HC640; 74HCT640 but has true (non-inverting) outputs.

2. Features

- Octal bidirectional bus interface
- Non-inverting 3-state outputs
- Multiple package options
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
 - ◆ MM EIA/JESD22-A115-A exceeds 200 V
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

3. Quick reference data

Table 1: Quick reference data
 $GND = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $t_r = t_f = 6\text{ ns}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Type 74HC245						
t_{PHL} , t_{PLH}	propagation delay An to Bn or Bn to An	$C_L = 15\text{ pF}$; $V_{CC} = 5\text{ V}$	-	7	-	ns
C_I	input capacitance		-	3.5	-	pF
$C_{I/O}$	input/output capacitance		-	10	-	pF
C_{PD}	power dissipation capacitance per transceiver	$V_I = GND\text{ to }V_{CC}$	[1] -	30	-	pF
Type 74HCT245						
t_{PHL} , t_{PLH}	propagation delay An to Bn or Bn to An	$C_L = 15\text{ pF}$; $V_{CC} = 5\text{ V}$	-	10	-	ns

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Table 1: Quick reference data ...continued

GND = 0 V; $T_{amb} = 25^{\circ}\text{C}$; $t_r = t_f = 6\text{ ns}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C_I	input capacitance		-	3.5	-	pF
$C_{I/O}$	input/output capacitance		-	10	-	pF
C_{PD}	power dissipation capacitance per transceiver	$V_I = \text{GND to } V_{CC} - 1.5\text{ V}$	[1] -	30	-	pF

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

 f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

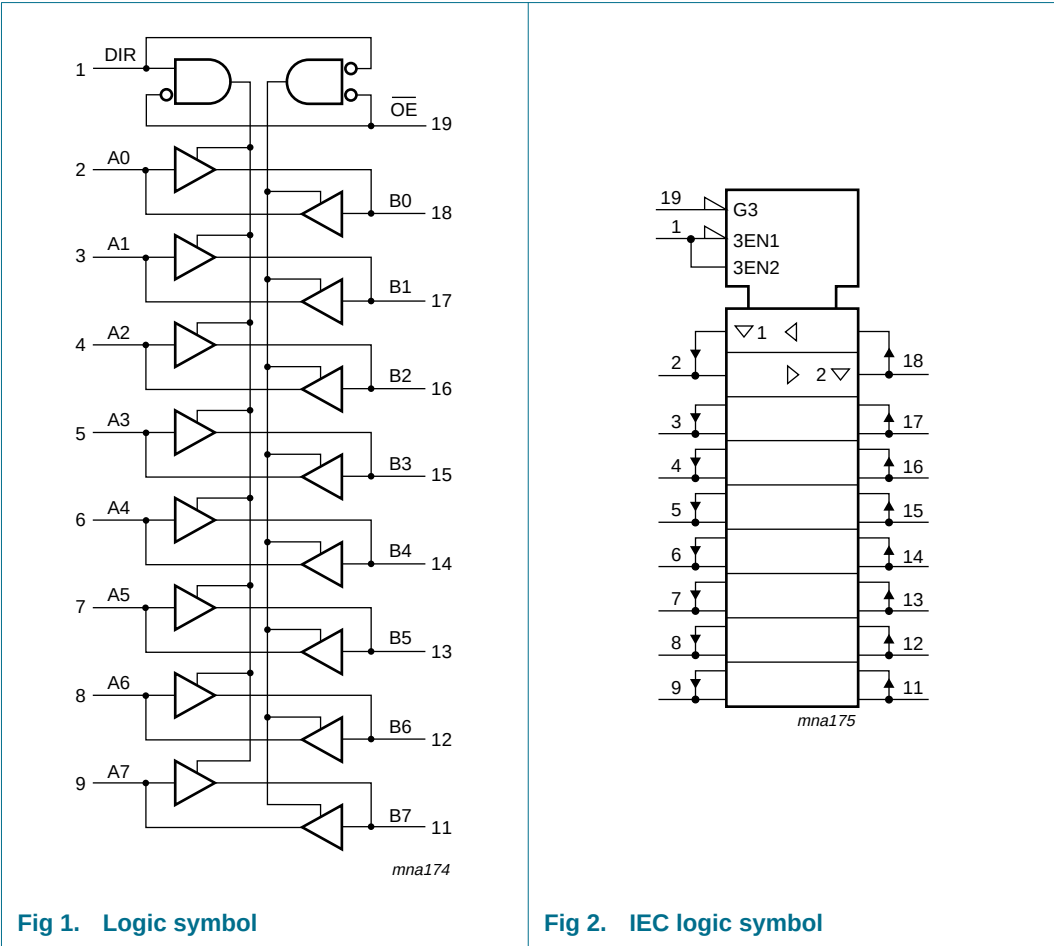
4. Ordering information

Table 2: Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC245N	-40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HC245D	-40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74HC245PW	-40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74HC245DB	-40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74HC245BQ	-40 °C to +125 °C	DHVQFN20	plastic dual-in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1
74HCT245N	-40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HCT245D	-40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74HCT245PW	-40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74HCT245DB	-40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74HCT245BQ	-40 °C to +125 °C	DHVQFN20	plastic dual-in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1

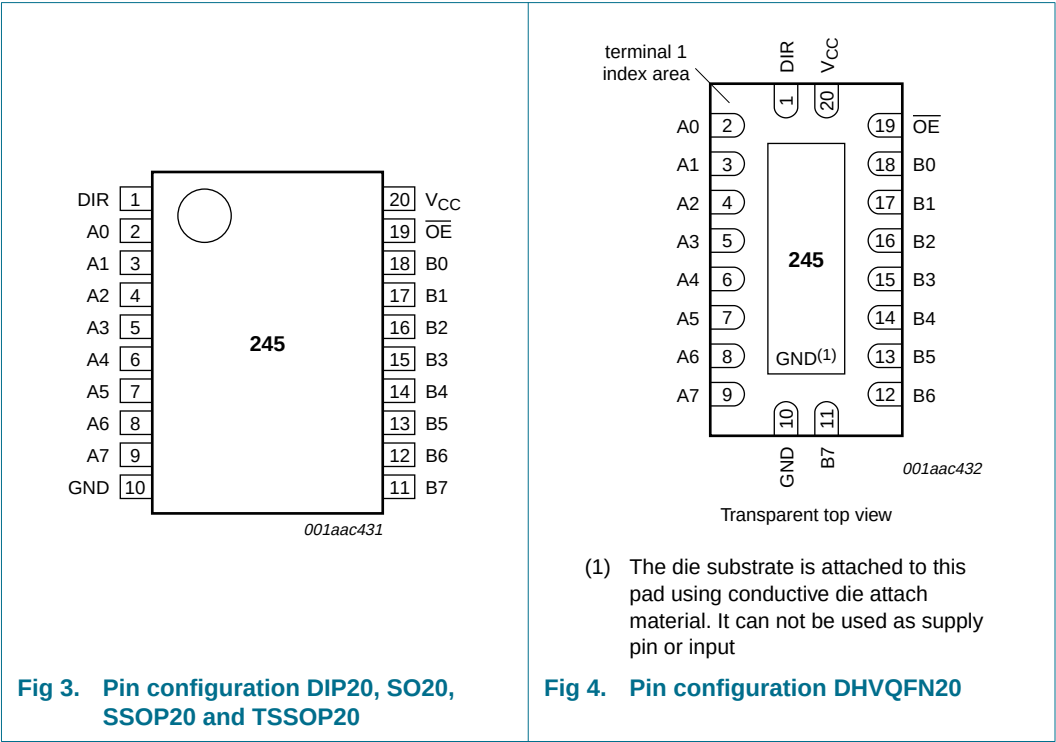


5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3: Pin description

Symbol	Pin	Description
DIR	1	direction control
A0	2	data input/output
A1	3	data input/output
A2	4	data input/output
A3	5	data input/output
A4	6	data input/output
A5	7	data input/output
A6	8	data input/output
A7	9	data input/output
GND	10	ground (0 V)
B7	11	data input/output
B6	12	data input/output
B5	13	data input/output
B4	14	data input/output
B3	15	data input/output
B2	16	data input/output

Table 3: Pin description ...continued

Symbol	Pin	Description
B1	17	data input/output
B0	18	data input/output
$\overline{\text{OE}}$	19	output enable input (active LOW)
V _{CC}	20	supply voltage

7. Functional description

7.1 Function table

Table 4: Function table [1]

Input		Input/output	
$\overline{\text{OE}}$	DIR	A _n	B _n
L	L	A = B	input
L	H	input	B = A
H	X	Z	Z

- [1] H = HIGH voltage level;
 L = LOW voltage level;
 X = don't care;
 Z = high-impedance OFF-state.

8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input diode current	V _I < -0.5 V or V _I > V _{CC} + 0.5 V	-	±20	mA
I _{OK}	output diode current	V _O < -0.5 V or V _O > V _{CC} + 0.5 V	-	±20	mA
I _O	output source or sink current	V _O = -0.5 V to V _{CC} + 0.5 V	-	±35	mA
I _{CC} , I _{GND}	V _{CC} or GND current		-	±70	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[1]		
	DIP20 package		-	750	mW
	SO20, SSOP20, TSSOP20 and DHVQFN20 packages		-	500	mW

- [1] For DIP20 packages: above 70 °C, P_{tot} derates linearly with 12 mW/K.
 For SO20 packages: above 70 °C, P_{tot} derates linearly with 8 mW/K.
 For SSOP20 and TSSOP20 packages: above 60 °C, P_{tot} derates linearly with 5.5 mW/K.
 For DHVQFN20 packages: above 60 °C, P_{tot} derates linearly with 4.5 mW/K.

9. Recommended operating conditions

Table 6: Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Type 74HC245						
V_{CC}	supply voltage		2.0	5.0	6.0	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
t_r, t_f	input rise and fall times	$V_{CC} = 2.0\text{ V}$	-	-	1000	ns
		$V_{CC} = 4.5\text{ V}$	-	6.0	500	ns
		$V_{CC} = 6.0\text{ V}$	-	-	400	ns
T_{amb}	ambient temperature		-40	-	+125	°C
Type 74HCT245						
V_{CC}	supply voltage		4.5	5.0	5.5	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
t_r, t_f	input rise and fall times	$V_{CC} = 4.5\text{ V}$	-	6.0	500	ns
T_{amb}	ambient temperature		-40	-	+125	°C

10. Static characteristics

Table 7: Static characteristics type 74HC245

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25\text{ °C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0\text{ V}$	1.5	1.2	-	V
		$V_{CC} = 4.5\text{ V}$	3.15	2.4	-	V
		$V_{CC} = 6.0\text{ V}$	4.2	3.2	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0\text{ V}$	-	0.8	0.5	V
		$V_{CC} = 4.5\text{ V}$	-	2.1	1.35	V
		$V_{CC} = 6.0\text{ V}$	-	2.8	1.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}\text{ or }V_{IL}$				
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 2.0\text{ V}$	1.9	2.0	-	V
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$	4.4	4.5	-	V
		$I_O = -20\text{ }\mu\text{A}; V_{CC} = 6.0\text{ V}$	5.9	6.0	-	V
		$I_O = -6.0\text{ mA}; V_{CC} = 4.5\text{ V}$	3.98	4.32	-	V
		$I_O = -7.8\text{ mA}; V_{CC} = 6.0\text{ V}$	5.48	5.81	-	V

Table 7: Static characteristics type 74HC245 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$	-	0	0.1	V
		$I_O = 20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$	-	0	0.1	V
		$I_O = 20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$	-	0	0.1	V
		$I_O = 6.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$	-	0.15	0.26	V
		$I_O = 7.8\ \text{mA}; V_{CC} = 6.0\ \text{V}$	-	0.16	0.26	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0\ \text{V}$	-	-	± 0.1	μA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0\ \text{V}$	-	-	± 0.5	μA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0\ \text{A}$; $V_{CC} = 6.0\ \text{V}$	-	-	8.0	μA
C_I	input capacitance		-	3.5	-	pF
$C_{I/O}$	input/output capacitance		-	10	-	pF
$T_{amb} = -40\ ^\circ\text{C}$ to $+85\ ^\circ\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0\ \text{V}$	1.5	-	-	V
		$V_{CC} = 4.5\ \text{V}$	3.15	-	-	V
		$V_{CC} = 6.0\ \text{V}$	4.2	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0\ \text{V}$	-	-	0.5	V
		$V_{CC} = 4.5\ \text{V}$	-	-	1.35	V
		$V_{CC} = 6.0\ \text{V}$	-	-	1.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = -20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$	1.9	-	-	V
		$I_O = -20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$	4.4	-	-	V
		$I_O = -20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$	5.9	-	-	V
		$I_O = -6.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$	3.84	-	-	V
		$I_O = -7.8\ \text{mA}; V_{CC} = 6.0\ \text{V}$	5.34	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$	-	-	0.1	V
		$I_O = 20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$	-	-	0.1	V
		$I_O = 20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$	-	-	0.1	V
		$I_O = 6.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$	-	-	0.33	V
		$I_O = 7.8\ \text{mA}; V_{CC} = 6.0\ \text{V}$	-	-	0.33	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0\ \text{V}$	-	-	± 1.0	μA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0\ \text{V}$	-	-	± 5.0	μA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0\ \text{A}$; $V_{CC} = 6.0\ \text{V}$	-	-	80	μA
$T_{amb} = -40\ ^\circ\text{C}$ to $+125\ ^\circ\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0\ \text{V}$	1.5	-	-	V
		$V_{CC} = 4.5\ \text{V}$	3.15	-	-	V
		$V_{CC} = 6.0\ \text{V}$	4.2	-	-	V

Table 7: Static characteristics type 74HC245 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0\text{ V}$	-	-	0.5	V
		$V_{CC} = 4.5\text{ V}$	-	-	1.35	V
		$V_{CC} = 6.0\text{ V}$	-	-	1.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}	-	-	-	-
		$I_O = -20\text{ }\mu\text{A}$; $V_{CC} = 2.0\text{ V}$	1.9	-	-	V
		$I_O = -20\text{ }\mu\text{A}$; $V_{CC} = 4.5\text{ V}$	4.4	-	-	V
		$I_O = -20\text{ }\mu\text{A}$; $V_{CC} = 6.0\text{ V}$	5.9	-	-	V
		$I_O = -6.0\text{ mA}$; $V_{CC} = 4.5\text{ V}$	3.7	-	-	V
		$I_O = -7.8\text{ mA}$; $V_{CC} = 6.0\text{ V}$	5.2	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}	-	-	-	-
		$I_O = 20\text{ }\mu\text{A}$; $V_{CC} = 2.0\text{ V}$	-	-	0.1	V
		$I_O = 20\text{ }\mu\text{A}$; $V_{CC} = 4.5\text{ V}$	-	-	0.1	V
		$I_O = 20\text{ }\mu\text{A}$; $V_{CC} = 6.0\text{ V}$	-	-	0.1	V
		$I_O = 6.0\text{ mA}$; $V_{CC} = 4.5\text{ V}$	-	-	0.4	V
		$I_O = 7.8\text{ mA}$; $V_{CC} = 6.0\text{ V}$	-	-	0.4	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0\text{ V}$	-	-	± 1.0	μA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0\text{ V}$	-	-	± 10.0	μA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0\text{ A}$; $V_{CC} = 6.0\text{ V}$	-	-	160	μA

Table 8: Static characteristics type 74HCT245

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25\text{ }^\circ\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	2.0	1.6	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	1.2	0.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5\text{ V}$	-	-	-	-
		$I_O = -20\text{ }\mu\text{A}$	4.4	4.5	-	V
		$I_O = -6\text{ mA}$	3.98	4.32	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5\text{ V}$	-	-	-	-
		$I_O = 20\text{ }\mu\text{A}$	-	0	0.1	V
		$I_O = 6.0\text{ mA}$	-	0.15	0.26	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$	-	-	± 0.1	μA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 5.5\text{ V}$; $V_O = V_{CC}$ or GND per input pin; other inputs at V_{CC} or GND; $I_O = 0\text{ A}$	-	-	± 0.5	μA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0\text{ A}$; $V_{CC} = 5.5\text{ V}$	-	-	8.0	μA

Table 8: Static characteristics type 74HCT245 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
ΔI_{CC}	additional quiescent supply current per input pin	$V_I = V_{CC} - 2.1$ V; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A				
	An or Bn inputs		-	40	144	μ A
	$\overline{OE}$ input		-	150	540	μ A
	DIR input		-	90	324	μ A
C_I	input capacitance		-	3.5	-	pF
$C_{I/O}$	input/output capacitance		-	10	-	pF
$T_{amb} = -40$ °C to $+85$ °C						
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	-	-	0.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5$ V				
		$I_O = -20$ μ A	4.4	-	-	V
		$I_O = -6$ mA	3.84	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5$ V				
		$I_O = 20$ μ A	-	-	0.1	V
		$I_O = 6.0$ mA	-	-	0.33	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	± 1.0	μ A
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 5.5$ V; $V_O = V_{CC}$ or GND per input pin; other inputs at V_{CC} or GND; $I_O = 0$ A	-	-	± 5.0	μ A
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μ A
ΔI_{CC}	additional quiescent supply current per input pin	$V_I = V_{CC} - 2.1$ V; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A				
	An or Bn inputs		-	-	180	μ A
	$\overline{OE}$ input		-	-	675	μ A
	DIR input		-	-	405	μ A
$T_{amb} = -40$ °C to $+125$ °C						
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	-	-	0.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5$ V				
		$I_O = -20$ μ A	4.4	-	-	V
		$I_O = -6$ mA	3.7	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5$ V				
		$I_O = 20$ μ A	-	-	0.1	V
		$I_O = 6.0$ mA	-	-	0.4	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	± 1.0	μ A
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 5.5$ V; $V_O = V_{CC}$ or GND per input pin; other inputs at V_{CC} or GND; $I_O = 0$ A	-	-	± 10	μ A

Table 8: Static characteristics type 74HCT245 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μ A
ΔI_{CC}	additional quiescent supply current per input pin	$V_I = V_{CC} - 2.1$ V; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A				
	An or Bn inputs		-	-	196	μ A
	$\overline{OE}$ input		-	-	735	μ A
	DIR input		-	-	441	μ A

11. Dynamic characteristics

Table 9: Dynamic characteristics type 74HC245GND = 0 V; test circuit see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25$ °C						
t_{PHL}, t_{PLH}	propagation delay An to Bn or Bn to An	see Figure 5				
		$V_{CC} = 2.0$ V	-	25	90	ns
		$V_{CC} = 4.5$ V	-	9	18	ns
		$V_{CC} = 5.0$ V; $C_L = 15$ pF	-	7	-	ns
		$V_{CC} = 6.0$ V	-	7	15	ns
t_{PZH}, t_{PZL}	3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	see Figure 6				
		$V_{CC} = 2.0$ V	-	30	150	ns
		$V_{CC} = 4.5$ V	-	11	30	ns
		$V_{CC} = 6.0$ V	-	9	26	ns
t_{PHZ}, t_{PLZ}	3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	see Figure 6				
		$V_{CC} = 2.0$ V	-	41	150	ns
		$V_{CC} = 4.5$ V	-	15	30	ns
		$V_{CC} = 6.0$ V	-	12	26	ns
t_{THL}, t_{TLH}	output transition time	see Figure 5				
		$V_{CC} = 2.0$ V	-	14	60	ns
		$V_{CC} = 4.5$ V	-	5	12	ns
		$V_{CC} = 6.0$ V	-	4	10	ns
C_{PD}	power dissipation capacitance per transceiver	$V_I = \text{GND to } V_{CC}$	[1] -	30	-	pF
$T_{amb} = -40$ °C to $+85$ °C						
t_{PHL}, t_{PLH}	propagation delay An to Bn or Bn to An	see Figure 5				
		$V_{CC} = 2.0$ V	-	-	115	ns
		$V_{CC} = 4.5$ V	-	-	23	ns
		$V_{CC} = 6.0$ V	-	-	20	ns

Table 9: Dynamic characteristics type 74HC245 ...continuedGND = 0 V; test circuit see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_{PZH}, t_{PZL}	3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	see Figure 6				
		$V_{CC} = 2.0 \text{ V}$	-	-	190	ns
		$V_{CC} = 4.5 \text{ V}$	-	-	38	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	33	ns
t_{PHZ}, t_{PLZ}	3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	see Figure 6				
		$V_{CC} = 2.0 \text{ V}$	-	-	190	ns
		$V_{CC} = 4.5 \text{ V}$	-	-	38	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	33	ns
t_{THL}, t_{TLH}	output transition time	see Figure 5				
		$V_{CC} = 2.0 \text{ V}$	-	-	75	ns
		$V_{CC} = 4.5 \text{ V}$	-	-	15	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	13	ns
$T_{amb} = -40 \text{ }^{\circ}\text{C to } +125 \text{ }^{\circ}\text{C}$						
t_{PHL}, t_{PLH}	propagation delay An to Bn or Bn to An	see Figure 5				
		$V_{CC} = 2.0 \text{ V}$	-	-	135	ns
		$V_{CC} = 4.5 \text{ V}$	-	-	27	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	23	ns
t_{PZH}, t_{PZL}	3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	see Figure 6				
		$V_{CC} = 2.0 \text{ V}$	-	-	225	ns
		$V_{CC} = 4.5 \text{ V}$	-	-	45	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	38	ns
t_{PHZ}, t_{PLZ}	3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn	see Figure 6				
		$V_{CC} = 2.0 \text{ V}$	-	-	225	ns
		$V_{CC} = 4.5 \text{ V}$	-	-	45	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	38	ns
t_{THL}, t_{TLH}	output transition time	see Figure 5				
		$V_{CC} = 2.0 \text{ V}$	-	-	90	ns
		$V_{CC} = 4.5 \text{ V}$	-	-	18	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	15	ns

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

 f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Table 10: Dynamic characteristics type 74HCT245

GND = 0 V; test circuit see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
t _{PHL} , t _{PLH}	propagation delay An to Bn or Bn to An	see Figure 5				
		V _{CC} = 4.5 V	-	12	22	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	10	-	ns
t _{PZH} , t _{PZL}	3-state output enable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn	V _{CC} = 4.5 V; see Figure 6	-	16	30	ns
t _{PHZ} , t _{PLZ}	3-state output disable time $\overline{\text{OE}}$ to An or OE to Bn	V _{CC} = 4.5 V; see Figure 6	-	16	30	ns
t _{THL} , t _{TLH}	output transition time	V _{CC} = 4.5 V; see Figure 5	-	5	12	ns
C _{PD}	power dissipation capacitance per transceiver	V _I = GND to V _{CC} – 1.5 V	[1] -	30	-	pF
T_{amb} = –40 °C to +85 °C						
t _{PHL} , t _{PLH}	propagation delay An to Bn or Bn to An	V _{CC} = 4.5 V; see Figure 5	-	-	28	ns
t _{PZH} , t _{PZL}	3-state output enable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn	V _{CC} = 4.5 V; see Figure 6	-	-	38	ns
t _{PHZ} , t _{PLZ}	3-state output disable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn	V _{CC} = 4.5 V; see Figure 6	-	-	38	ns
t _{THL} , t _{TLH}	output transition time	V _{CC} = 4.5 V; see Figure 5	-	-	15	ns
T_{amb} = –40 °C to +125 °C						
t _{PHL} , t _{PLH}	propagation delay An to Bn or Bn to An	V _{CC} = 4.5 V; see Figure 5	-	-	33	ns
t _{PZH} , t _{PZL}	3-state output enable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn	V _{CC} = 4.5 V; see Figure 6	-	-	45	ns
t _{PHZ} , t _{PLZ}	3-state output disable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn	V _{CC} = 4.5 V; see Figure 6	-	-	45	ns
t _{THL} , t _{TLH}	output transition time	V _{CC} = 4.5 V; see Figure 5	-	-	18	ns

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;f_o = output frequency in MHz;C_L = output load capacitance in pF;V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

12. Waveforms

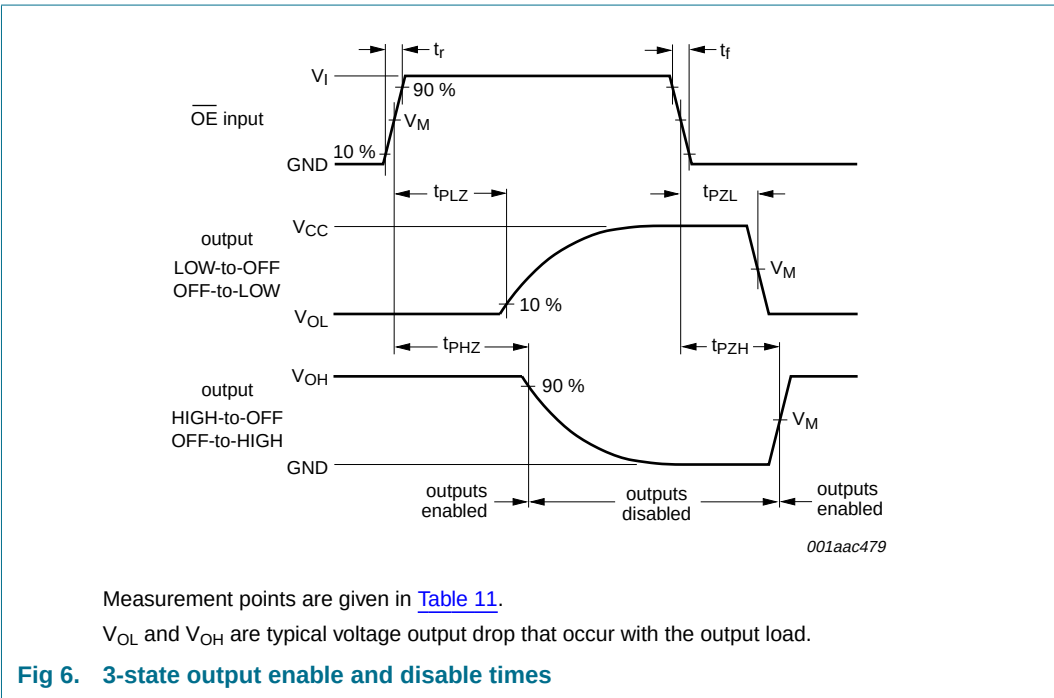
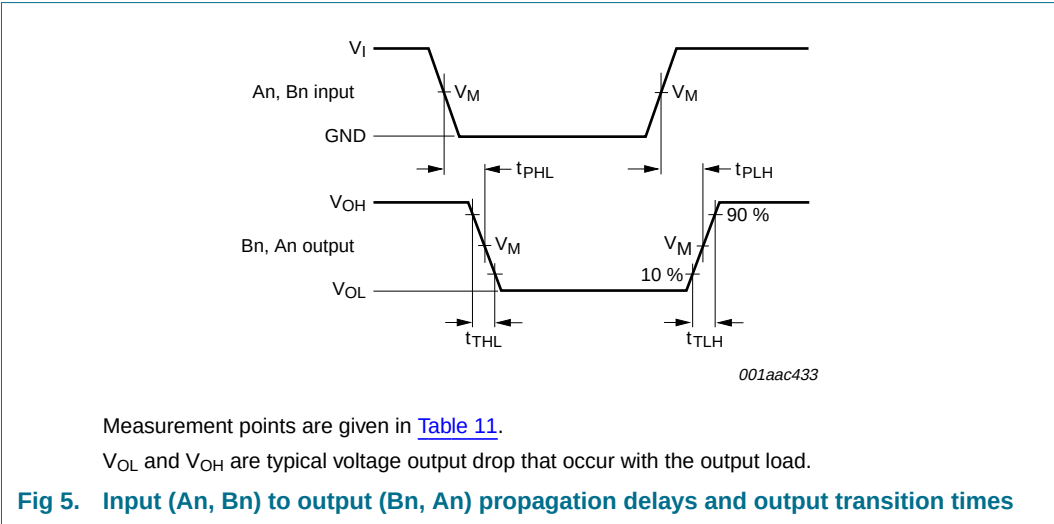


Table 11: Measurement points

Type	Input	Output
	V_M	V_M
74HC245	$0.5V_{CC}$	$0.5V_{CC}$
74HCT245	1.3 V	1.3 V

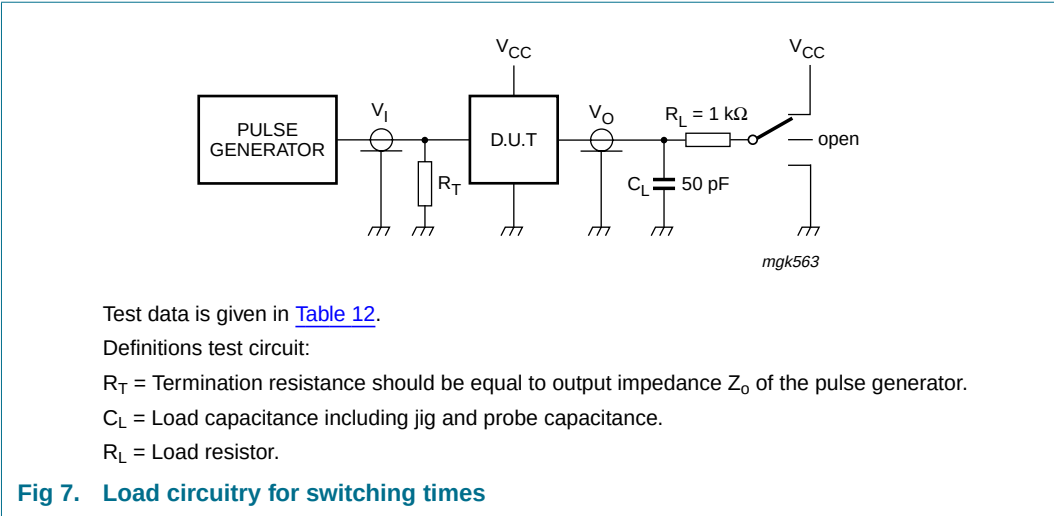


Table 12: Test data

Type	Input		Test		
	V_I	t_r, t_f	t_{PHL}, t_{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
74HC245	V_{CC}	6 ns	open	GND	V_{CC}
74HCT245	3 V	6 ns	open	GND	V_{CC}

13. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1

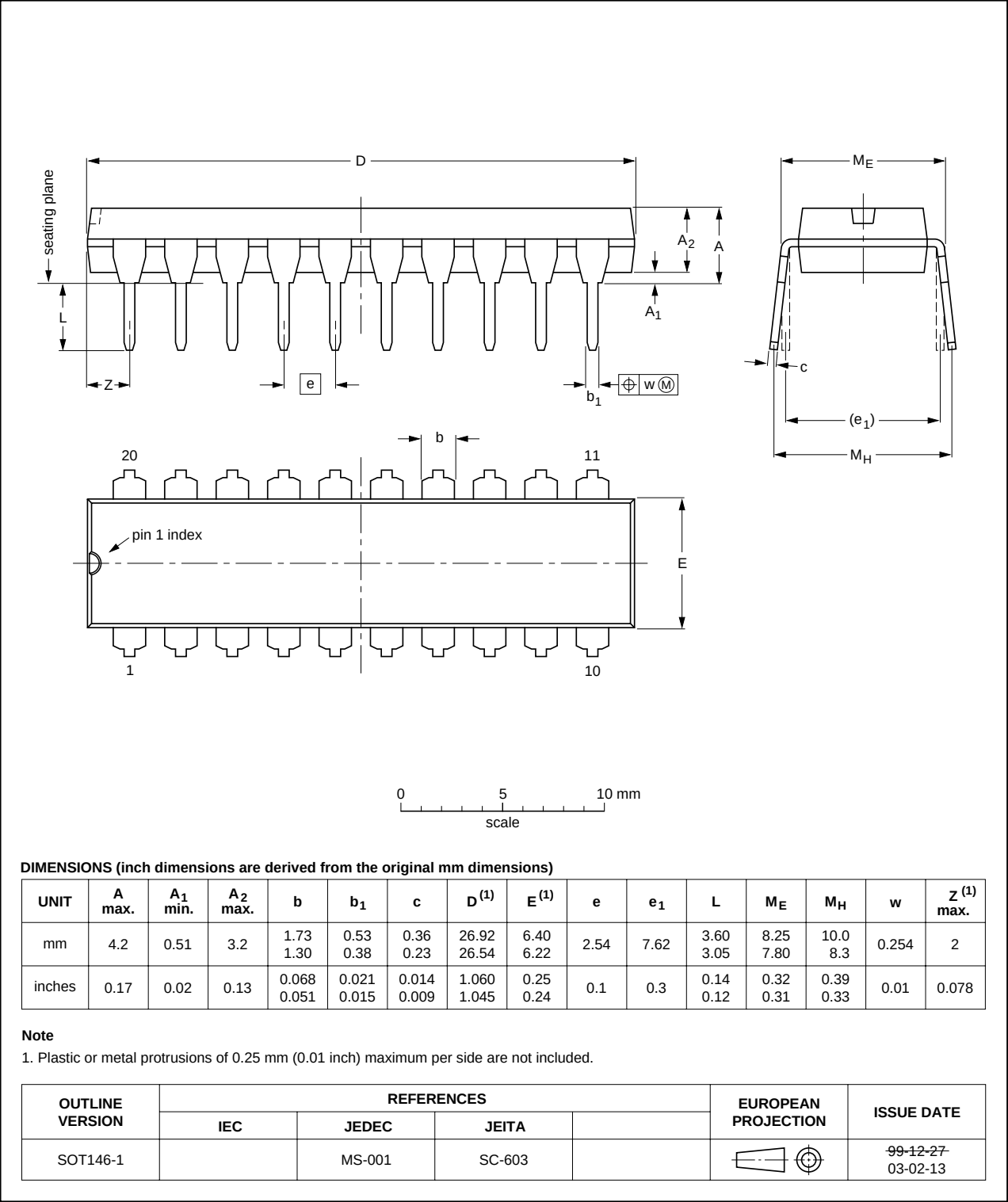


Fig 8. Package outline SOT146-1 (DIP20)

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

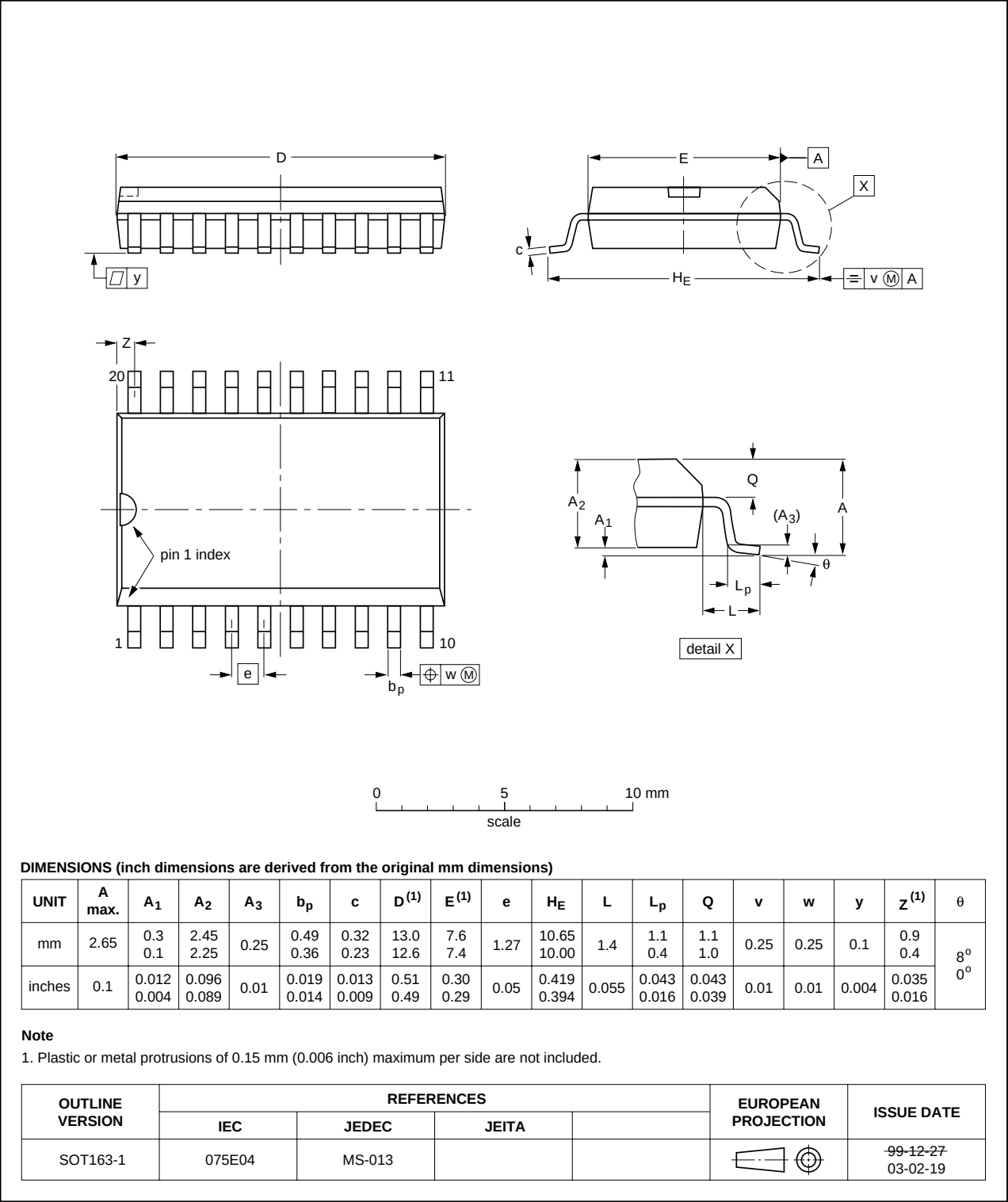


Fig 9. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

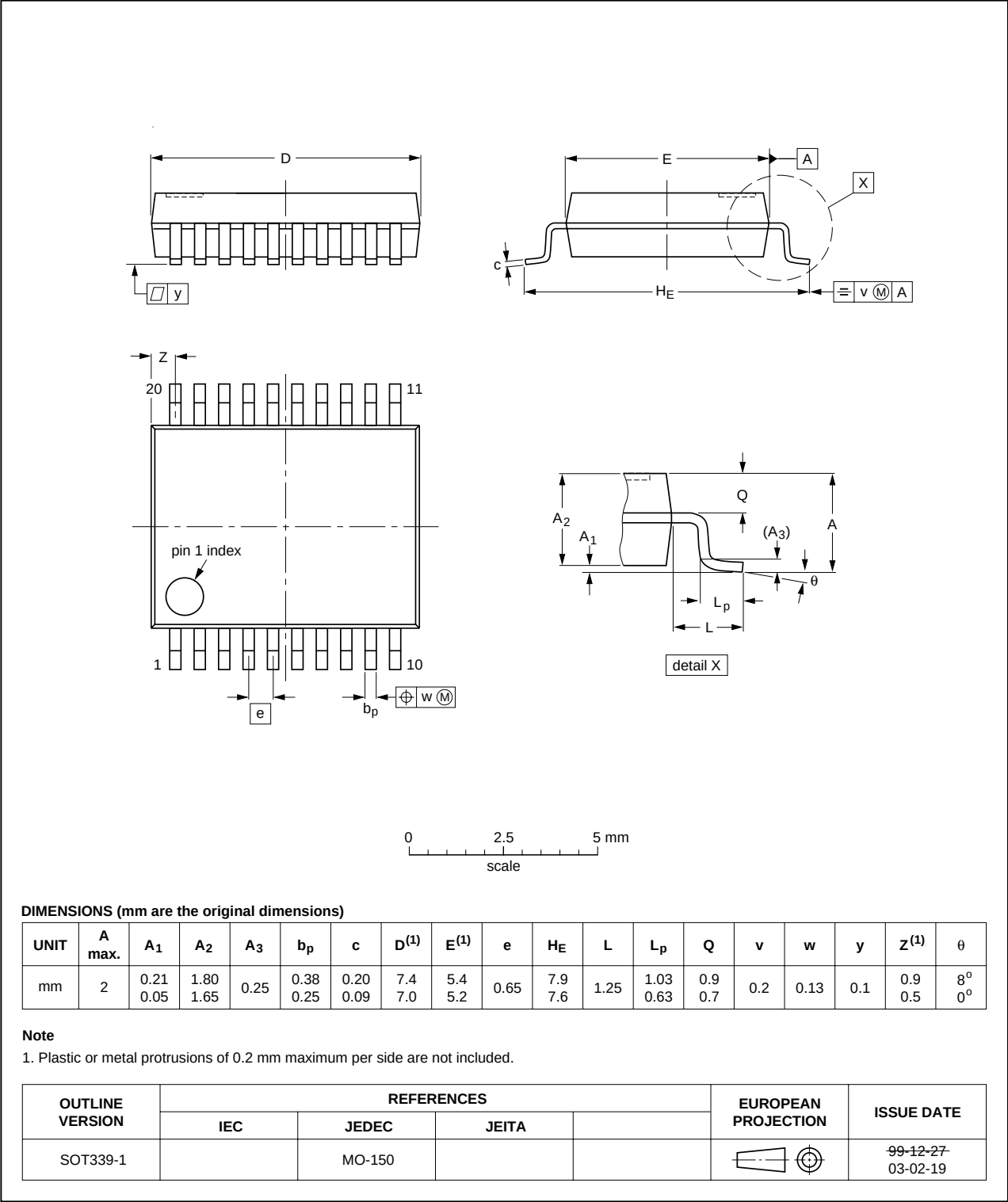


Fig 10. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

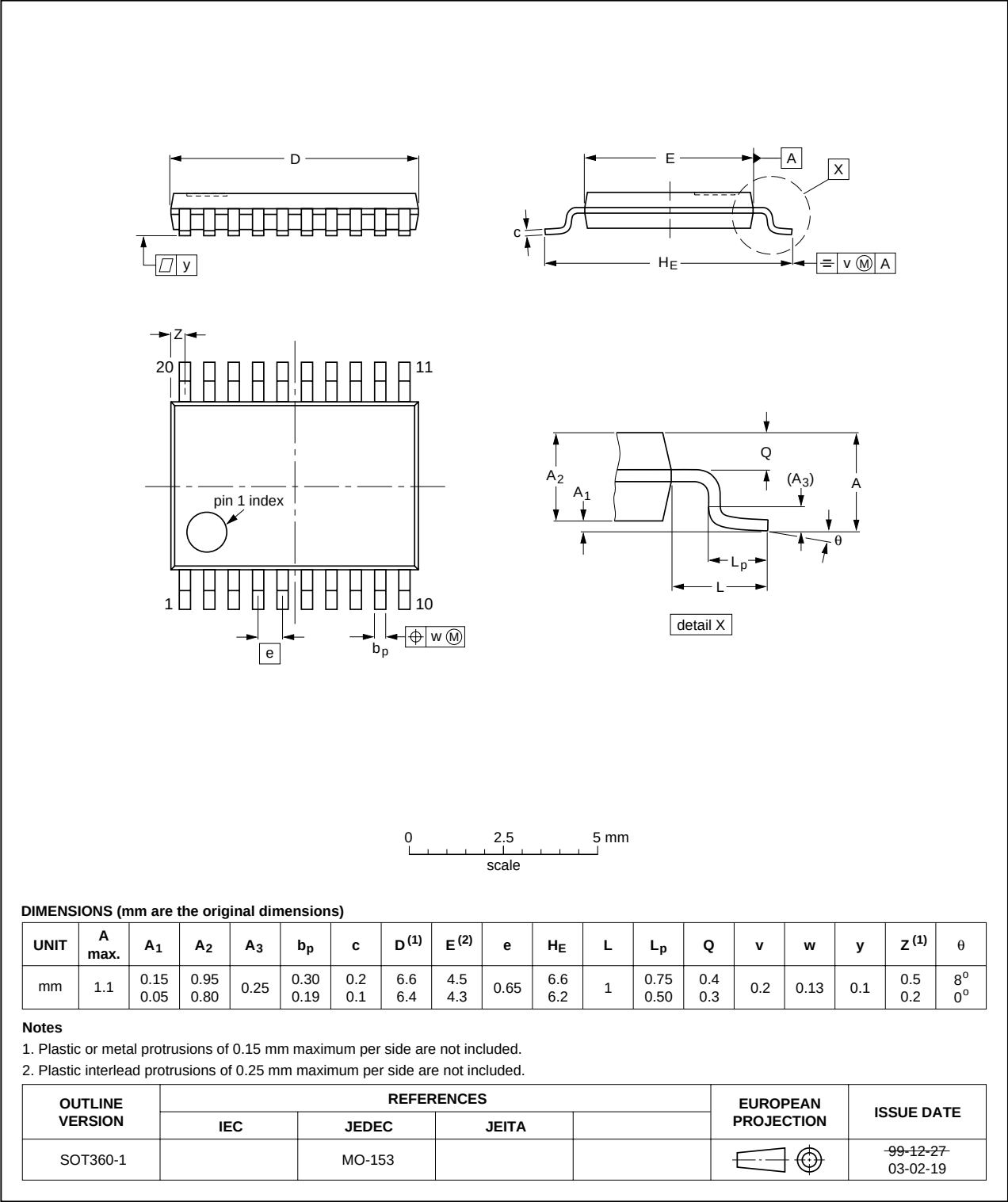


Fig 11. Package outline SOT360-1 (TSSOP20)

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm

SOT764-1

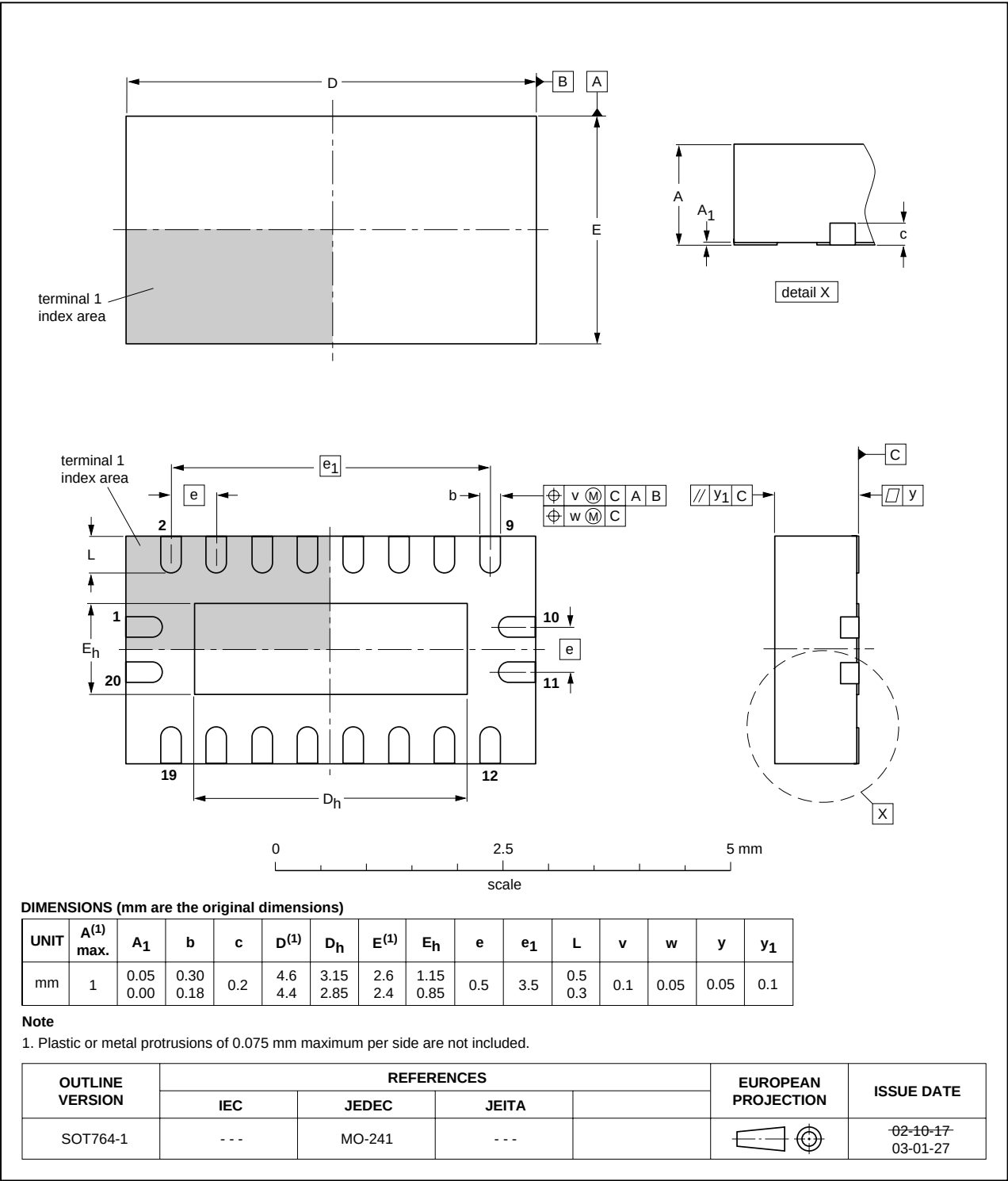


Fig 12. Package outline SOT764-1 (DHVQFN20)



14. Revision history

Table 13: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
74HC_HCT245_3	20050131	Product data sheet	-	9397 750 14502	74HC_HCT245_CNV_2
Modifications:					
- The format of this data sheet is redesigned to comply with the new presentation and information standard of Philips Semiconductors Section 4 "Ordering information", Section 6 "Pinning information" and Section 13 "Package outline" are modified to include the DHVQFN20 package.					
74HC_HCT245_CNV_2	19930930	Product specification	-	-	-

15. Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

16. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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